

LEADING PERFORMANCE OF LIGHT SENSING WITH NEW PHOTODIODE TECHNOLOGY

Where innovation meets the challenging demand

ElFys provides innovative photodetector technology with sensitivity better than anything seen so far. We design, develop and manufacture better photodiodes to help our customers achieve competitive edge with new solutions in a wide range of light sensing applications:

ANALYZE & DISPLAY Analytical instruments Health monitoring PHOTODETECTOR ntensit ARRAY Safety & security sensing and imaging Medical x-ray imaging ш LIGHT SOURCE Wavelength Industrial & environmental sensing SENSOR BOARD Key benefits to your applications DIFFRACTION GRATING High responsivity (> 96% EQE) over entire optical 0.8 spectrum range (200 nm to 1050 nm) Photosensitivity (A/W) ElFys photodiode 0.7 Ultra wide sensing angle with extremely high 0.6 absorbance (> 95% @ 60°) 0.5 EQE=100% Superior responsivity in ultraviolet wavelength range 0.4 (no signal losses in the photodetector surface layer) 0.3 0.2 Other state-of-the-art photodiodes Customized design with optimal electrical properties 0.1 0.0 200 400 600 800 1000 ESA TRL 5 ready, critical performance verified in relevant Wavelength (nm) environment Data certified by PTB Core technology: Black Silicon Induced Junction Nano-engineered surface structure Defect-free induced junction Advanced ALD coating technique Patents Our photodiode technology is protected by our patent families worldwide